

TOSHIBA Photocoupler Photorelay

TLP197D

PC Card Modems **PBX**

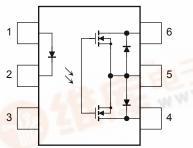
Measurement Equipment

The Toshiba TLP197D consists of an aluminum gallium arsenide infrared emitting diode optically coupled to a photo-MOSFET in a SOP package.

TLP197D is housed in a compact and thin SOP package and has characteristics of high-withstanding voltage and low ON-state resistance, which enable TLP197D to be applied in hook switches, dial-pulse switches for modems and facsimiles, and switches for test circuit switching in PBXes.

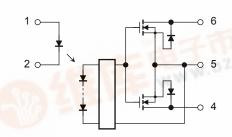
- 6-pin SOP (2.54SOP6): Height = 2.1 mm, pitch = 2.54 mm
- Normally open (1-form-A) device
- Peak OFF-state voltage: 200 V (min)
- Trigger LED current: 3 mA (max)
- ON-state current: 200 mA (max)
- ON-state resistance: 8 Ω (max)
- Isolation voltage: 1500 Vrms (min)
- UL recognized: UL1577, file no. E67349

Pin Configuration (top view)

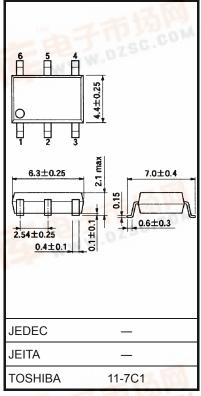


- 1: Anode
- 2: Cathode
- 4: Drain D1
- 5: Source
- 6: Drain D2

Schematic







Weight: 0.13 g (typ.)



Absolute Maximum Ratings (Ta = 25°C)

Characteristics			Symbol	Rating	Unit	
	Forward current		lF	50	mA	
LED	Forward current d (Ta ≧ 25°C)	erating	ΔI _F /°C	-0.5	mA/°C	
	Peak forward curr (100 μs pulse, 100		I _{FP}	1	А	
	Reverse voltage		V_{R}	5	V	
	Junction temperat	ure	Tj	125	°C	
	Off-state output te	rminal voltage	V _{OFF}	200	V	
	On-state current	A connection		200		
		B connection	I _{ON}	200	mA	
ctor		C connection		400		
Detector	On-state current derating	A connection		-2.0		
		B connection	Δl _{ON} /°C	-2.0	mA/°C	
	(Ta ≧ 25°C)	C connection		-4.0		
	Junction temperat	ure	Tj	125	°C	
Ope	rating temperature	range	T _{opr}	-40 to 85	°C	
Stora	age temperature ra	nge	T _{stg}	-55 to 125	°C	
Lead	d soldering tempera	ture (10 s)	T _{sol}	260	°C	
	tion voltage 1 min, R.H. ≦ 60%) (Note 1)	BVS	1500	Vrms	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

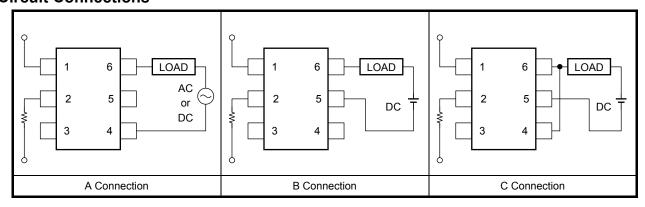
Note 1: Pins 1, 2 and 3 are shorted together, and pins 4, 5 and 6 are shorted together.

Recommended Operating Conditions

Characteristics	Symbol	Min	Тур.	Max	Unit
Supply voltage	V_{DD}	_	_	160	V
Forward current	lF	5	7.5	25	mA
On-state current	I _{ON}	_	_	130	mA
Operating temperature	T _{opr}	-20	_	60	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

Circuit Connections



Electrical Characteristics (Ta = 25°C)

	Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
	Forward voltage	V _F	I _F = 10 mA	1.0	1.15	1.3	V
LED	Reverse current	I _R	V _R = 5 V	_	_	10	μА
	Capacitance	C _T	V = 0, f = 1 MHz	_	30	_	pF
ec-	Off-state current	l _{OFF}	V _{OFF} = 200 V	_	_	1	μА
Detec- tor	Capacitance	C _{OFF}	V = 0, f = 1 MHz	_	100	_	pF

Coupled Electrical Characteristics (Ta = 25°C)

Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Trigger LED current		I _{FT}	I _{ON} = 200 mA	_	1	3	mA
Return LED current		I _{FC}	I _{OFF} = 100 μA	0.1	_	_	mA
	A connection		$I_{ON} = 200 \text{ mA}, I_F = 5 \text{ mA}$	_	5	8	
On-state resistance	B connection	R _{ON}	I _{ON} = 200 mA, I _F = 5 mA	_	3	5	Ω
	C connection		I _{ON} = 400 mA, I _F = 5 mA		1.4	_	

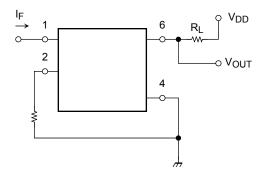
Isolation Characteristics (Ta = 25°C)

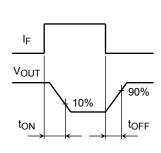
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Capacitance input to output	Cs	$V_S = 0$, $f = 1$ MHz	_	8.0	_	pF
Isolation resistance	R _S	V _S = 500 V, R.H. ≦ 60%	5×10^{10}	10 ¹⁴	_	Ω
		AC, 1 min	1500		_	Vrms
Isolation voltage	BV_S	AC, 1 s, in oil	_	3000	_	VIIIIS
		DC, 1 min, in oil	—	3000	_	Vdc

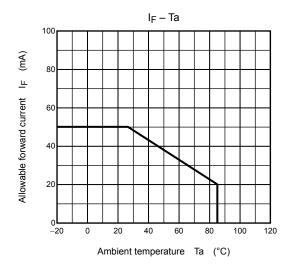
Switching Characteristics (Ta = 25°C)

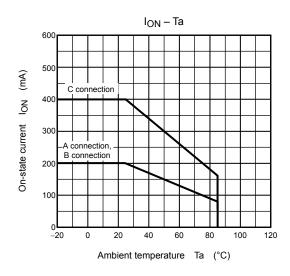
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Turn-on time	t _{ON}	$R_L = 200 \Omega$ (Note 2)	_	0.6	1.5	ms
Turn-off time	toff	$V_{DD} = 20 \text{ V}, I_F = 5 \text{ mA}$	_	0.1	1.0	ms

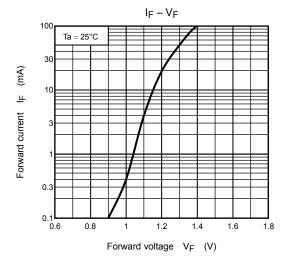
Note 2: Switching time test circuit

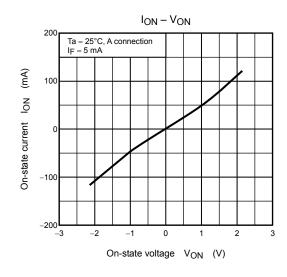


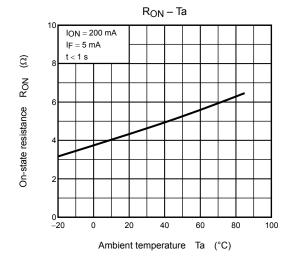


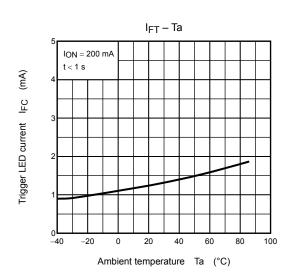


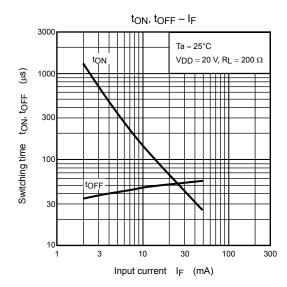


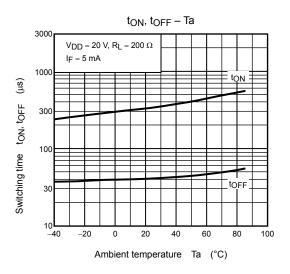


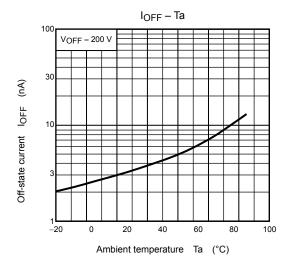












5

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